



M T B F (E I A J R C R - 9 1 0 2)

Model	BRNS6
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No.	P a r t s		Q'ty of Device	Failure rate [10 ⁻⁶ /H]	R e f e r e n c e
1	I C	Monolithic	1	0.0240	
2		Hybrid	0	0.0000	
3	Transistors		3	0.1991	
4	Diodes		3	0.0595	
5	LED•Optocouplers		0	0.0000	
6	Resistors		21	0.0042	
7	Capacitors		13	0.0962	
8	Transformer•Choke Coil		1	0.0230	
9	Connectors		108	0.0148	
10	Others		0	0.0000	
Total Failure Rate [10 ⁻⁶ /H]				0.4208	

M T B F [H]	2,380,000
Ambient Temperature [°C]	—
Load Factor [%]	—